

What is Claimed is;

1. A capacitor device, comprising:

aplurality of conductive pattern electrodes electrically separated by a separation groove;

a capacitor element in which at least either one of an anode lead and a cathode lead is connected via a thin metal wire having a fusing feature to the conductive pattern electrode, and

an insulating resin for covering the capacitor element, the thin metal wire, and the conductive pattern electrode except for a face and for integrally supporting the conductive pattern electrode, the thin metal wire, and the capacitor element.

2. The capacitor device according to claim 1, wherein the anode lead and the cathode lead are both connected to the conductive pattern electrode via the thin metal wire having a fusing feature, respectively.

3. The capacitor device according to claim 1, wherein the anode lead is derived at a dislocated position and is connected to the conductive pattern electrode via the thin metal wire having a fusing feature.

4. The capacitor device according to claim 1, wherein the anode lead is subjected to plating to form a flat section, and which is connected to the conductive pattern electrode via the

thin metal wire having a fusing feature.

5. A capacitor device comprising;

aplurality of conductive pattern electrodes electrically separated by a separation groove;

a capacitor element in which at least either one of an anode lead and a cathode lead is connected via a thin metal wire having a fusing feature to first and second conductive pattern electrode, respectively,

a circuit element bare chip attached to the pad of a third conductive pattern electrode ; and

an insulating resin for covering the bare chip, the thin metal wire, and the first, second and third conductive pattern electrodes except for a face and for integrally supporting the first, second and third conductive pattern electrodes, the capacitor element, and the bare chip.

6. The capacitor device according to claim 1 or 5, wherein a capacity of a fusing current is adjusted depending on the number of thin metal wires.

7. The capacitor device according to claim 1 or 5, wherein the capacitor element is made in such a manner that tantalum in the form of metal powders and the anode lead are subjected to pressurization and molding, and a dielectric body is made by a tantalum oxide .